Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

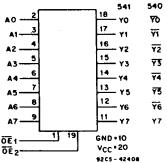
Texas Instruments
CD74ACT541E

For any questions, you can email us directly: sales@integrated-circuit.com



CD54/74AC540, CD54/74AC541 CD54/74ACT540, CD54/74ACT541





Octal Buffer/Line Drivers, 3-State

CD74AC/ACT540 - Inverting CD74AC/ACT541 - Non-Inverting

Type Features:

- Buffered inputs
- Typical propagation delay: 4.5 ns @ V_{CC} = 5 V, T_A = 25° C, C_L = 50 pF

FUNCTIONAL DIAGRAM

The CD54/74AC540, -541, and CD54/74ACT540, -541 octal buffer/line drivers use the RCA ADVANCED CMOS technology. The CD54/74AC/ACT540 are inverting 3-state buffers having two active-LOW output enables. The CD54/74AC/ACT541 are non-inverting 3-state buffers having two active-LOW output enables.

The CD74AC540, -541, and CD74ACT540, -541 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Industrial (–40 to +85°C) and Extended Industrial/Military (–55 to +125°C).

The CD54AC540, -541, and CD54ACT540, -541, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- ± 24-mA output drive current
 - Fanout to 15 FAST® ICs
 - Drives 50-ohm transmission lines

®FAST is a Registered Trademark of Fairchild Semiconductor Corp.

TRUTH TABLE

	CD54/74AC	/ACT540	
INPUTS		OUTPUTS	
ŌE1, ŌE2	Α	Υ	
L	L	Н	
L	н	L	
н	x	Z	

TRUTH TABLE

	CD54/74AC	/ACT541	
INPUTS		OUTPUTS	
OE1, OE2	Α	Υ	
L	L	L	
L	н	Н	
н	X	Z	

H = High Voltage L = Low Voltage X = Immaterial

Z = High Impedance



CD54/74AC540, CD54/74AC541 CD54/74ACT540, CD54/74ACT541

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE (V _{CC}) -0.5 to 6 V
DC INPUT DIODE CURRENT, I_{IK} (for $V_{I} < -0.5$ or $V_{I} > V_{CC} + 0.5$ V)
DC OUTPUT DIODE CURRENT, I_{OK} (for $V_O < -0.5$ or $V_O > V_{CC} + 0.5$ V)
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, IO (for VO > -0.5 or VO < VCC + 0.5 V)
DC V _{CC} OR GROUND CURRENT (I _{CC} or I _{GND})
PACKAGE THERMAL IMPEDANCE, θJA (see Note 1): E package
M package
STORAGE TEMPERATURE (T _{stq})
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79 \text{ mm})$ from case for 10 s maximum
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only +300°C

^{*} For up to 4 outputs per device: add ± 25 mA for each additional output.

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIN	LAUTC		
CHARACTERISTIC	MIN.	MAX.	UNITS	
Supply-Voltage Range, V _{cc} *: (For T _A = Full Package-Temperature Range) AC Types ACT Types	1.5 4.5	5.5 5.5	V	
DC Input or Output Voltage, V _i , V _o	0	V _{cc}	V	
Operating Temperature, T _A :	-55	+125	°C	
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)	0 0 0	50 20 10	ns/V ns/V ns/V	

^{*}Unless otherwise specified, all voltages are referenced to ground.

TERMINAL ASSIGNMENT DIAGRAMS



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.



Technical Data	
CDEA/7AACEAO CDEA/7AACEA1	
CD54/74AC540, CD54/74AC541	
CD54/74ACT540, CD54/74ACT541	

STATIC ELECTRICAL CHARACTERISTICS: AC Series

				AMBIENT TEMPERATURE (TA) - °C							
CHARACTERISTICS		TEST CONDITIONS		V _{cc}	+:	+25		o +85	-55 to +125		UNITS
		V ₁ (V)	l _o (mA)	(Ÿ)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2	_	1.2		1.2		
Voltage	ViH			3	2.1	_	2.1		2.1] v
				5.5	3.85	-	3.85	_	3.85		<u> </u>
Low-Level Input				1.5		0.3		0.3		0.3	
Voltage	VIL		Į	3		0.9	_	0.9		0.9	_ v
			1	5.5	-	1.65	_	1.65		1.65	
High-Level Output			-0.05	1.5	1.4	- ·	1.4		1.4		
Voltage	V _{он}	ViH	-0.05	- 3	2.9		2.9		2.9	_	
		or	-0.05	4.5	4.4	_	. 4.4		4.4		}
		VıL	-4	3	2.58	_	2.48		2.4] v
			-24	4.5	3.94	_	3.8		3.7]
		#, * {	-75	5.5	_		3.85	_	_	_]
		7, 1	-50	5.5	_		_		3.85	_]
Low-Level Output		·	0.05	1.5	_	0.1	_	0.1	l –	0.1	
Voltage	Vol	VIH	0.05	3	_	0.1	_	0.1		0.1	1
		or	0.05	4.5	_	0.1		0.1	_	0.1	1
		V _{IL}	12	3		0.36	_	0.44	_	0.5	V
			24	4.5	_	0.36	_	0.44	_	0.5]
		#. * {	75	5.5	_		_	1.65		_]
		"'	50	5.5			_	_	_	1.65	1
Input Leakage Current	l ₁	V _{cc} or GND		5.5	_	±0.1	_	±1		±1	μΑ
3-State Leakage		ViH									
Current	loz	or					1				
		V ₁ L	‡ 	-	İ		}		1		
		Vo=		5.5	-	±0.5	_	±5		±10	μΑ
		Vcc	İ								
		or			ļ				İ		
		GND	1								
Quiescent Supply Current, MSI	lcc	V _{cc} or GND	0	5.5	_	8		80	_	160	μА

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.



CD54/74AC540, CD54/74AC541 CD54/74ACT540, CD54/74ACT541

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

					AMBIEN'	T TEMPE	RATURE	(T _A) - °	С]	
CHARACTERISTI	CHARACTERISTICS		TEST CONDITIONS		+	+25		o +85	-55 to +125		UNITS
			I _o (mA)	V _{cc} (V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.]
High-Level Input Voltage	VIH			4.5 to 5.5	2	_	2	_	2	_	v
Low-Level Input Voltage	ViL			4.5 to 5.5	_	0.8		0.8	_	0.8	v
High-Level Output		V _{IH}	-0.05	4.5	4.4		4.4		4.4	<u> </u>	
Voltage	V _{OH}	or V _{IL}	-24	4.5	3.94		3.8		3.7		V
		#, * {	-75	5.5	_	_	3.85		_] '
		" }	-50	5.5	_	_	_		3.85	_	
Low-Level Output Voltage		VIH	0.05	4.5	_	0.1		0.1		0.1	
	Vol	or V _{IL}	24	4.5	_	0.36		0.44	_	0.5	l v l
		#. * }	75	5.5		_		1.65] `
			50	5.5	_	_			_	1.65	
Input Leakage Current	l,	V _{cc} or GND		5.5	_	±0.1	_	±1	_	. ±1	μΑ
3-State Leakage Current	loz	V _{IH} or V _{IL} V _O = V _{CC} or GND		5.5	_	±0.5		±5	_	±10	μΑ
Quiescent Supply Current, MSI	lcc	V _{cc} or GND	0	5.5	_	8	_	80	-	160	μΑ
Additional Quiescent Supply Current per Input Pin TTL Inputs High ΔIcc 1 Unit Load		V _{cc} -2.1		4.5 to 5.5		2.4		2.8	wronen	3	mA

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

ACT INPUT LOADING TABLE

INPUT	UNIT LOAD*					
	540	541				
DATA	1.42	0.5				
OE1, OE2	1.3	1.3				

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

^{*} Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.



CD54/74AC540, CD54/74AC541 CD54/74ACT540, CD54/74ACT541

SWITCHING CHARACTERISTICS: AC Series; t_r , t_t = 3 ns, C_L = 50 pF

			AMBI	ENT TEMPE	RATURE (Γ _A) - °C		
CHARACTERISTICS	SYMBOL	v (v)	-40 1	o +85	-55 t	o +125	UNITS	
		(*)	MIN.	MIN. MAX.		MAX.	7	
Propagation Delays: Data to Output AC540	tpLH tpHL	1.5 3.3* 5†	2.4 1.8	77 8.6 6.2	2.4 1.7	85 9.5 6.8	ns	
AC541	t _{PLH} t _{PHL}	1.5 3.3 5	2.8 2.1	89 9.9 7.1	2.7 2	98 10.9 7.8	ns	
Enable, to Output to Output	t _{PZL} t _{PZH}	1.5 3.3 5	4.6 3.1	136 16.4 10.9	4.5 3	150 18 12	ns	
Disable to Output to Output	t _{PLZ} t _{PHZ}	1.5 3.3 5	3.9 3.1	136 13.6 10.9	3.8 3	150 15 12	ns	
Power Dissipation Capacitance AC540 AC541	C _{PD} ‡		- 60 Typ. 60 Typ. - 60 Typ. 60 Typ.			pF		
Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C				V	
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5	1 Typ. @ 25°C			V		
Input Capacitance	Cı	_	_	10	_	10	pF	
3-State Output Capacitance	Co	_	_	15	_	15	pF	

SWITCHING CHARACTERISTICS: ACT Series; t,, t, = 3 ns, C, = 50 pF

			AMBI	ENT TEMPE	RATURE (1	(v) - °C	
CHARACTERISTICS	SYMBOL	V _{cc}	-40 1	o +85	-55 to	=125	UNITS
		(V)	MIN.	MAX.	MIN.	MAX.	
Propagation Delays: Data to Output ACT540	t _{PLH} t _{PHL}	5†	1.9	6.5	1.8	7.2	ns
ACT541	t _{PLH} t _{PHL}	5†	2.1	7.5	2.1	8.2	ns
Enable to Output	t _{PZL} t _{PZH}	5	3.5	12.2	3.4	13.4	ns
Disable to Output	t _{PLZ} t _{PHZ}	5	3.5	12.2	3.4	13.4	ns
Power Dissipation Capacitance ACT540 ACT541	С _{РО} § — 60 Тур. 60 Тур. 60 Тур. 60 Тур.			pF			
Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C			. V	
Max. (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5	1 Typ. @ 25°C			v	
Input Capacitance	Cı	_	Τ -	10	_	10	ρF
3-State Output Capacitance	Co	. —	_	15	_	15	pF

*3.3 V: min. is @ 3.6 V max. is @ 3 V

§C_{PD} is used to determine the dynamic power consumption, per channel.

For AC series, $P_D = V_{cc}^2 f_i (C_{PD} + C_L)$ For ACT series, $P_D = V_{cc}^2 f_i (C_{PD} + C_L) + V_{cc} \Delta I_{cc}$ where

†5 V: min. is @ 5.5 V

f_i = input frequency

C_L = output load capacitance

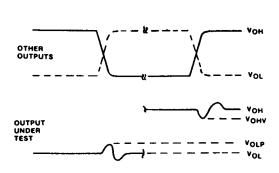
V_{cc} = supply voltage.

max. is @ 4.5 V



CD54/74AC540, CD54/74AC541 CD54/74ACT540, CD54/74ACT541

PARAMETER MEASUREMENT INFORMATION

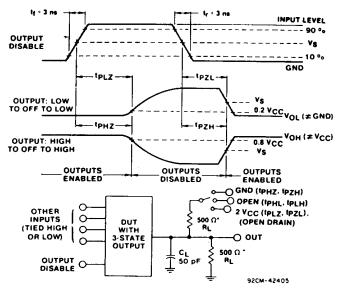


NOTES:

- VOHY AND VOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.
 INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS:
- 2. INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS: PRR S 1 MHz, t_F = 3 ne, t_F = 3 ne, SKEW 1 ne.

 3. R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED. IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 _{JF} CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

9205-42406



*FOR AC SERIES ONLY: WHEN VCC = 1.5 V, RL = 1 k Ω

Fig. 1 - Simultaneous switching transient waveforms.

Fig. 2 - Three-state propagation delay waveforms and test circuit.

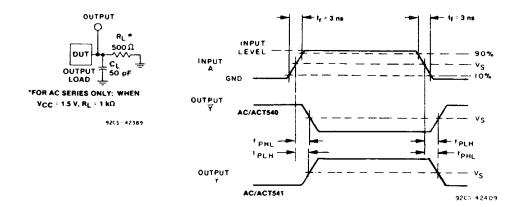


Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	CD54/74ACT
Input Level	V _{cc}	3 V
Input Switching Vottage, Vs	0.5 V _{cc}	1.5 V
Output Switching Voltage, V ₅	0.5 V _{cc}	0.5 V _{CC}



Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

9-Aug-2016

PACKAGING INFORMATION

Orderable Device Lead/Ball Finish MSL Peak Temp Status Package Type Package Pins Package Eco Plan Op Temp (°C) **Device Marking** Samples Qty Drawing (6) CD54AC541F3A ACTIVE CDIP 20 TBD CD54AC541F3A A42 N / A for Pkg Type -55 to 125 Samples N / A for Pkg Type CD54ACT540F3A CD54ACT540F3A ACTIVE CDIF 20 1 TBD A42 -55 to 125 J Samples CD54ACT541F3A ACTIVE CDIP J 1 TBD A42 CD54ACT541F3A 20 N / A for Pkg Type -55 to 125 Samples CD74AC540M ACTIVE SOIC 25 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 AC540M DW 20 & no Sb/Br) CD74AC540M96 PREVIEW CU NIPDAU AC540M SOIC DW 20 2000 Green (RoHS Level-1-260C-UNLIM & no Sb/Br) CD74AC540ME4 ACTIVE SOIC DW 20 25 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 AC540M Samples & no Sb/Br) CD74AC541E ACTIVE PDIP CU NIPDAU CD74AC541E Ν 20 20 N / A for Pkg Type (RoHS) CD74AC541EE4 ACTIVE PDIP Ν 20 20 Pb-Free CU NIPDAU N / A for Pkg Type -55 to 125 CD74AC541E (RoHS) CD74AC541M ACTIVE SOIC DW 20 25 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 AC541M & no Sb/Br) CD74AC541M96 **ACTIVE** SOIC DW 20 2000 Green (RoHS **CU NIPDAU** Level-1-260C-UNLIM -55 to 125 AC541M Samples & no Sb/Br) CD74AC541M96E4 **ACTIVE** SOIC DW 20 2000 Green (RoHS **CU NIPDAU** Level-1-260C-UNLIM -55 to 125 AC541M Samples & no Sb/Br) SOIC CU NIPDAU Level-1-260C-UNLIM CD74AC541M96G4 ACTIVE AC541M DW 20 2000 Green (RoHS -55 to 125 Samples & no Sb/Br) CD74AC541MG4 ACTIVE SOIC CU NIPDAU Level-1-260C-UNLIM AC541M DW Green (RoHS -55 to 125 20 25 Samples & no Sb/Br) CD74AC541SM OBSOLETE SSOP Call TI Call TI DB 20 -55 to 125 TBD CD74AC541SM96 ACTIVE SSOP DB 20 2000 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 AC541SM Samples & no Sb/Br) Green (RoHS & no Sb/Br) CD74AC541SM96G4 ACTIVE SSOP DB 20 2000 **CU NIPDAU** Level-1-260C-UNLIM -55 to 125 AC541SM Samples CD74ACT540E ACTIVE PDIP Ν 20 20 Pb-Free **CU NIPDAU** N / A for Pkg Type -55 to 125 CD74ACT540E Samples (RoHS) CD74ACT540EE4 ACTIVE CU NIPDAU CD74ACT540E PDIP Ν 20 20 Pb-Free N / A for Pkg Type -55 to 125 Samples

Addendum-Page 1

(RoHS)



Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

9-Aug-2016

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74ACT540M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT540M	Samples
CD74ACT540M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT540M	Sample
CD74ACT540M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT540M	Sample
CD74ACT540MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT540M	Sample
CD74ACT541E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT541E	Sample
CD74ACT541EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT541E	Sample
CD74ACT541M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541M	Sample
CD74ACT541M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541M	Sample
CD74ACT541M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541M	Sample
CD74ACT541M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541M	Sample
CD74ACT541MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541M	Sample
CD74ACT541SM	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	-55 to 125		
CD74ACT541SM96	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541SM	Sample
CD74ACT541SM96E4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT541SM	Sample

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

Addendum-Page 2

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



Distributor of Texas Instruments: Excellent Integrated System Limited Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

9-Aug-2016

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that Pb-Free (RoHS): Its terms Lead-Free or Pb-Free mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

(9) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "--" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54AC541, CD54ACT540, CD54ACT541, CD74AC541, CD74ACT540, CD74ACT541:

- Catalog: CD74AC541, CD74ACT540, CD74ACT541
- Military: CD54AC541, CD54ACT540, CD54ACT541

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

Addendum-Page 3

Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

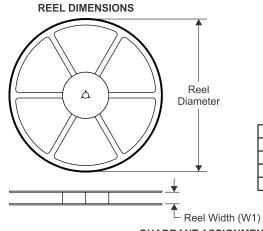
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

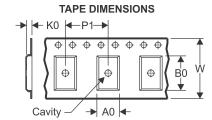


PACKAGE MATERIALS INFORMATION

www.ti.com 10-Aug-2016

TAPE AND REEL INFORMATION

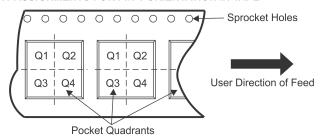




A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape

P1 Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC540M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74AC541M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74AC541SM96	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
CD74ACT540M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT541M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT541SM96	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1

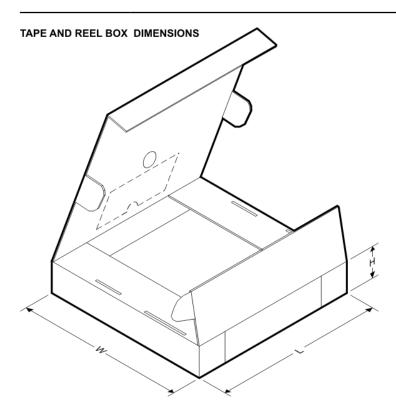
Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



PACKAGE MATERIALS INFORMATION

www.ti.com 10-Aug-2016



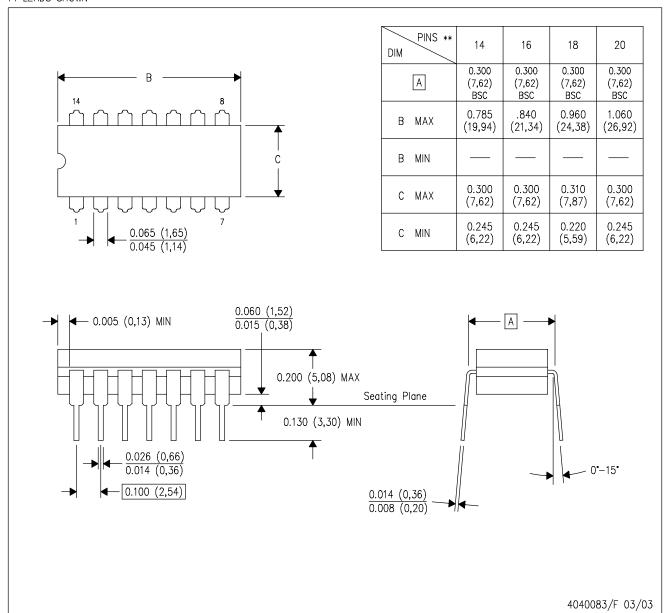
*All dimensions are nominal

All differentials are normal								
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74AC540M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74AC541M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74AC541SM96	SSOP	DB	20	2000	367.0	367.0	38.0	
CD74ACT540M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74ACT541M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74ACT541SM96	SSOP	DB	20	2000	367.0	367.0	38.0	

J (R-GDIP-T**)

CERAMIC DUAL IN-LINE PACKAGE

14 LEADS SHOWN



NOTES:

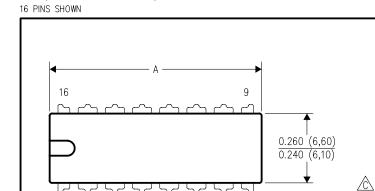
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



MECHANICAL DATA

N (R-PDIP-T**)

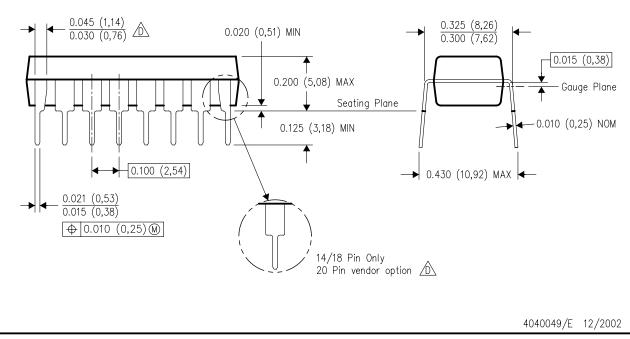
PLASTIC DUAL-IN-LINE PACKAGE



 $\frac{0.070 (1,78)}{0.045 (1,14)}$

8

PINS **	14	16	18	20
A MAX	0.775	0.775	0.920	1.060
	(19,69)	(19,69)	(23,37)	(26,92)
A MIN	0.745	0.745	0.850	0.940
	(18,92)	(18,92)	(21,59)	(23,88)
MS-001 VARIATION	AA	ВВ	AC	AD



NOTES:

- . All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





DW0020A

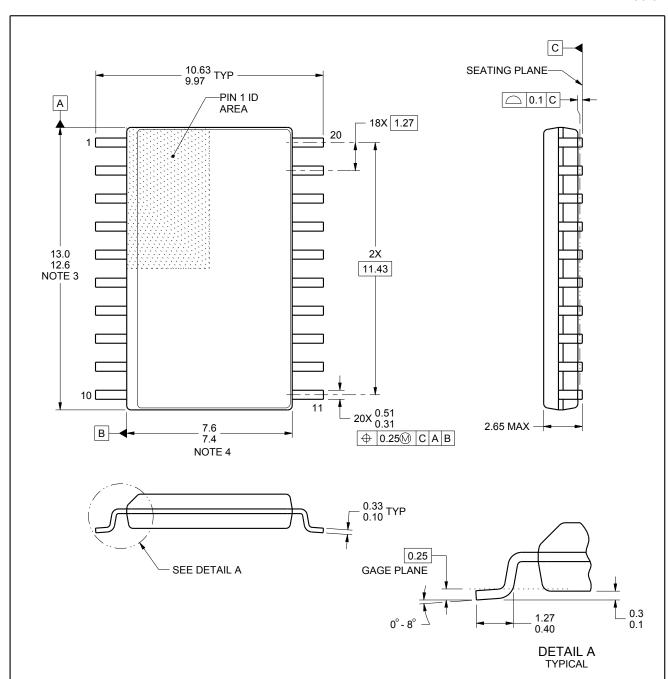
Signature of the second

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC

4220724/A 05/2016



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



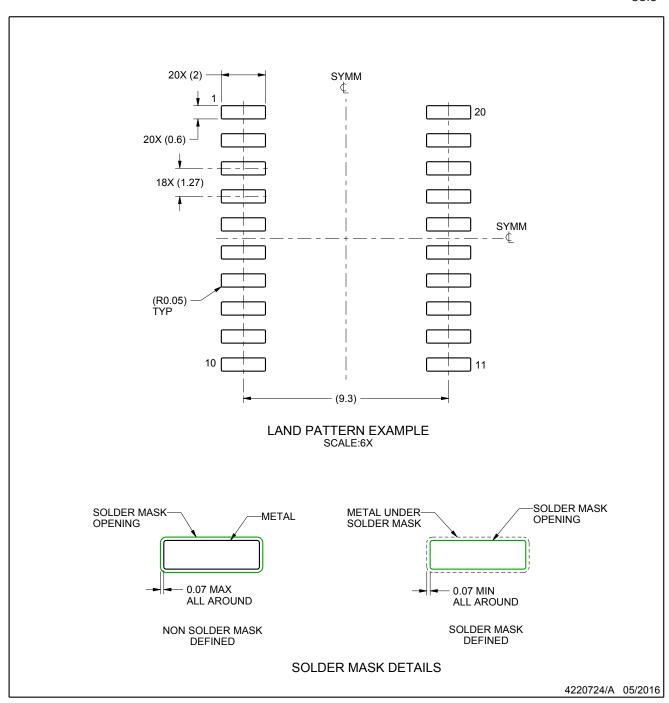


EXAMPLE BOARD LAYOUT

DW0020A

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



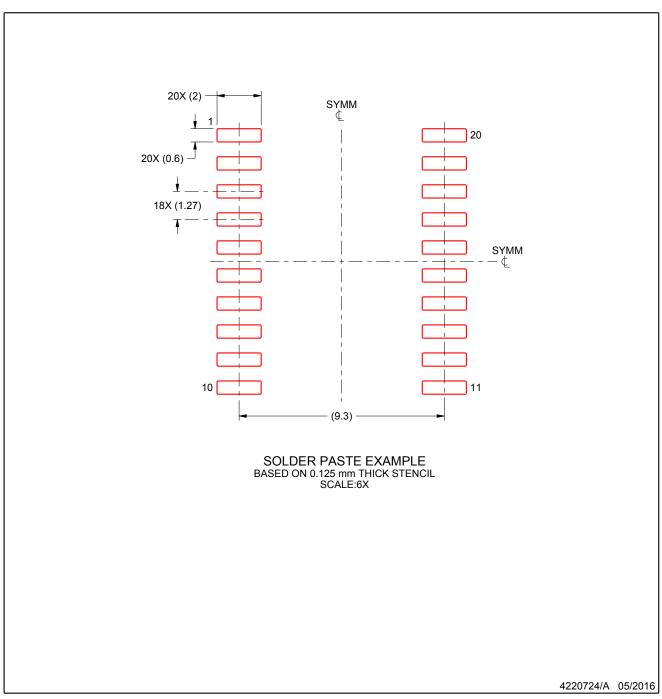


EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

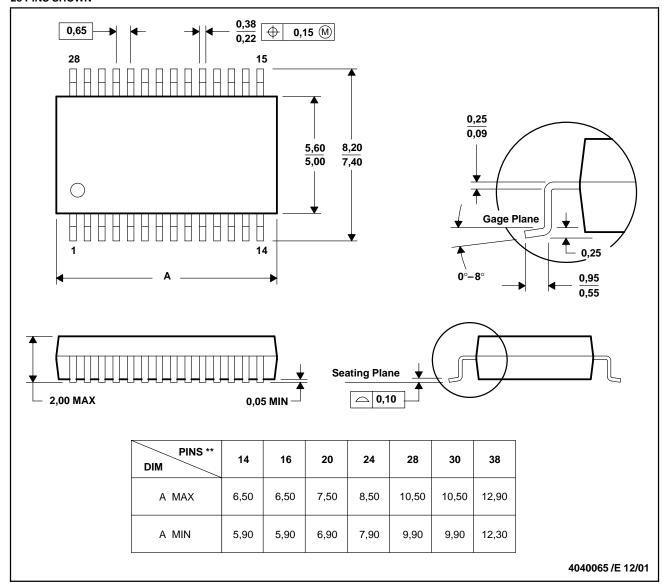
MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

28 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150





Distributor of Texas Instruments: Excellent Integrated System Limited Datasheet of CD74ACT541E - IC BUFF/DVR TRI-ST 8BIT 20DIP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have not been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications Computers and Peripherals **Data Converters** dataconverter.ti.com www.ti.com/computers **DLP® Products** Consumer Electronics www.ti.com/consumer-apps www.dlp.com DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Medical

Interface interface.ti.com www.ti.com/medical logic.ti.com Security www.ti.com/security Logic Power Mgmt Space, Avionics and Defense www.ti.com/space-avionics-defense power.ti.com

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

Products

OMAP Applications Processors TI E2E Community www.ti.com/omap e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity

> Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2016, Texas Instruments Incorporated